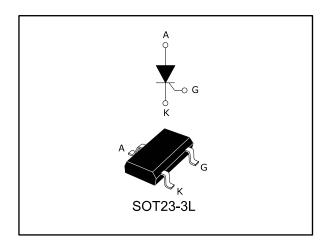
P0109AL



Sensitive high immunity 0.25 A SCR Thyristor

Datasheet - production data



Features

- I_{T(RMS)} 0.25 A
- Low 1 μA gate current
- High noise immunity 100 V/μs
- ECOPACK®2 compliant component

Applications

- Standby mode power supplies
- Smoke detectors
- DC 24/48 V proximity sensors
- Gate driver for large Thyristors
- Overvoltage crowbar protection
- Capacitive ignition circuit

Description

Thanks to highly sensitive triggering levels, the 0.25 A P0109AL SCR Thyristor is suitable for all applications where available gate current is limited. Its high immunity makes it ideal for high electric noise circuits.

The surface mount SOT23-3L package allows compact SMD based designs for automated manufacturing.

Table 1: Device summary

Symbol	Value	Unit
I _{T(RMS)}	0.25	Α
V _{DRM} /V _{RRM}	100	V
I _{GT}	1	μA
T _j max.	125	°C

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1 Characteristics

Table 2: Absolute maximum ratings (limiting values), Tj = 25 °C unless otherwise specified

Symbol	Parameter	Value	Unit			
I _{T(RMS)}	RMS on-state current (180 ° conduction angle)	0.25				
I _{T(AV)}	Average on-state current (180 ° conduction angle)	T _{amb} = 36 °C	0.16	А		
l	Non repetitive surge peak on-state curr	ent	$t_p = 8.3 \text{ ms}$	7	^	
I_{TSM} $(T_j initial = 25 °C$		$t_p = 10 \text{ ms}$	6	Α		
l ² t	I ² t value for fusing	$t_p = 10 \text{ ms}$	0.18	A ² s		
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$ $f = 60 \text{ Hz}$		T _j = 125 °C	50	A/µs	
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage	T _j = 125 °C	100	V		
I _{GM}	Peak gate current $t_p = 20 \mu s$		T _j = 125 °C	0.5	Α	
P _{G(AV)}	Average gate power dissipation	0.02	W			
T _{stg}	Storage junction temperature range	-40 to +150	°C			
Tj	Operating junction temperature	-40 to +125	°C			

Table 3: Electrical characteristics (Tj = 25 °C unless otherwise specified)

Symbol	Test conditions		Value	Unit	
I _{GT}	V 42 V D = 440 O		Max.	1	μΑ
V _G T	$V_D = 12 \text{ V}, R_L = 140 \Omega$			0.8	V
V_{GD}	$V_D = V_{DRM},~R_L$ = 3.3 k $\Omega,~R_{GK}$ = 1000 Ω	Min.	0.1	V	
V_{RG}	$I_{RG} = 10 \mu A$			8	V
lн	$I_T = 50 \text{ mA}, R_{GK} = 1000 \Omega$			6	mA
IL	$I_G = 1.2 \text{ x } I_{GT}, R_{GK} = 1000 \Omega$			7	mA
dV/dt	$V_D = 67 \text{ % } V_{DRM}, \ R_{GK} = 1000 \ \Omega$ $T_j = 125 \ ^{\circ}C$			100	V/µs

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit
V _{TM}	$I_{TM} = 0.4 \text{ A}, t_p = 380 \mu \text{s}$ $T_j = 25 ^{\circ}\text{C}$ Max.				V
Vто	Threshold voltage	Max.	1	V	
R_D	Dynamic resistance	T _j = 125 °C	Max.	1000	mΩ
1 /1	V V V D 1000 0	T _j = 25 °C	Max	1	μА
I _{DRM} /I _{RRM}	$V_D = V_{DRM}$; $V_R = V_{RRM}$, $R_{GK} = 1000 \Omega$	T _j = 125 °C	Max.	100	

Table 5: Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient (Mounted on FR4 with recommended pad layout)		°C/W



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1.1 Characteristics (curves)

0.00 0.02

0.04

0.06

0.08

0.10

0.14

0.16

0.18

Figure 2: Average and DC on-state current versus ambient temperature

0.30 | T(AV)(A) | 0.25 | 0.20 | 0.15 | 0.10 | 0.15 | 0.10 | 0.05 | 0.00 | 0.05 | 0.00 | 0.25 | 50 | 75 | 100 | 125

Figure 3: Relative variation of thermal impedance junction to ambient versus pulse duration

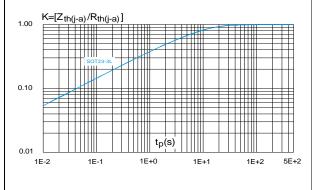


Figure 4: Gate trigger, holding, and latching currents with gate trigger voltage versus junction temperature

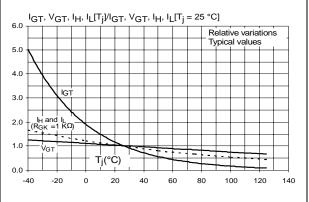


Figure 5: Relative variation of holding current versus gate-cathode resistance

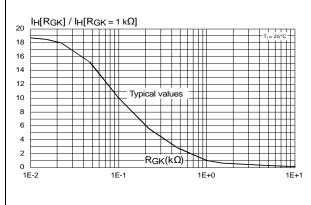
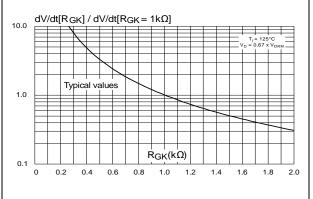


Figure 6: Relative variation of dV/dt immunity versus gate-cathode resistance



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6

5

Figure 7: Relative variation of dV/dt immunity versus gate-cathode capacitance

10

dV/dt[CGκ] / dV/dt[RGκ= 1κΩ, CGκ = 0 F]

10

RGK=1kΩ

C_{GK}(nF)

3

Figure 8: Surge peak on-state current versus

Figure 9: Non-repetitive surge peak on-state current for sinusoidal pulse (t_p< 10 ms)

100.0

100.0

100.0

100.0

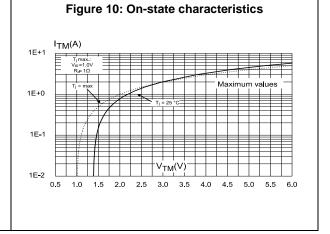
100.0

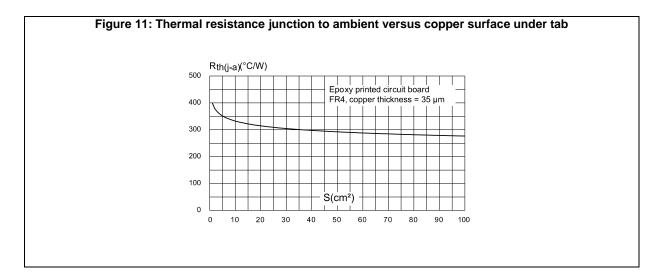
100.0

100.0

100.0

100.0





P0109AL Package information

2 **Package information**

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Lead-free package
- Halogen free molding resin
- Epoxy meets UL94, V0

SOT23-3L package information 2.1

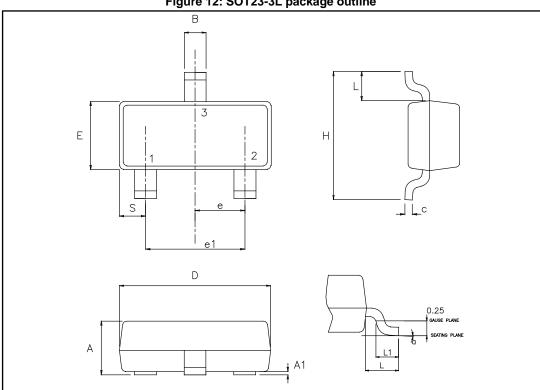


Figure 12: SOT23-3L package outline

This package drawing may slightly differ from the physical package. However, all the specified dimensions in the following table are guaranteed.

Table 6: SOT23-3L package mechanical data

	Dimensions					
Ref.	Millimeters		Inches ⁽¹⁾			
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.89		1.40	0.0350		0.0551
A1	0.00		0.10	0.0000		0.0039
В	0.30		0.51	0.0118		0.0201
С	0.085		0.18	0.0033		0.0071
D	2.75		3.04	0.1083		0.1197
е	0.85		1.05	0.0335		0.0413
e1	1.70		2.10	0.0669		0.0827
Е	1.20		1.75	0.0472		0.0689
Н	2.10		3.00	0.0827		0.1181
L		0.60			0.0236	
S	0.35		0.65	0.0138		0.256
L1	0.25		0.55	0.0098		0.0217
а	0°		8°	0°		8°

Notes:

0.97 0.48 0.95 2.89 0.99

Figure 13: SOT23-3L footprint in mm

This drawing may not be in scale; however, all the specified dimensions are guaranteed.

⁽¹⁾Dimension in inches are given for reference only.

P0109AL Ordering information

3 Ordering information

Figure 14: Ordering information scheme

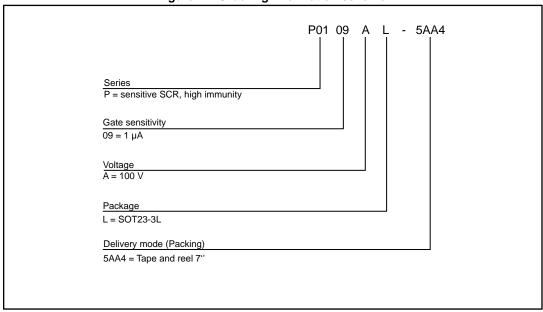


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
P0109AL 5AA4	P9A	SOT23-3L	0.01 g	3000	Tape and reel 7"

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
05-Jun-2017	1	Initial release.
09-Aug-2017	2	Updated drawing in cover page.

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